# Ultra High Accuracy, Low Iq, 500 mA Low Dropout Regulator

The NCP3334A is a high performance, low dropout regulator with accuracy of  $\pm 0.9\%$  over line and load. This device features ultra-low quiescent current and noise which encompasses all necessary characteristics demanded by today's consumer electronics. This unique device is guaranteed to be stable without a minimum load current requirement and stable with any type of capacitor as small as  $1.0 \,\mu\text{F}$ . The NCP3334A offers reverse bias protection. The device is available in a small 3x3 mm WDFN8 package.

#### Features

- High Accuracy Over Line and Load (±0.9% at 25°C)
- Ultra-Low Dropout Voltage at Full Load
- No Minimum Output Current Required for Stability
- Low Noise
- Low Shutdown Current
- Reverse Bias Protected
- 2.6 V to 12 V Supply Range
- Thermal Shutdown Protection
- Current Limitation
- Requires Only 1.0 µF Output Capacitance for Stability
- Stable with Any Type of Capacitor (including MLCC)
- These are Pb–Free Devices

### Applications

- Telecom Applications
- Cellular Base Stations
- Camcoders and Cameras
- Networking Systems, DSL/Cable Modems
- Cable Set-Top Box
- MP3/CD Players
- DSP Supply
- Displays and Monitors



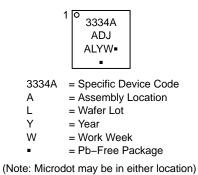
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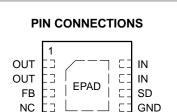
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WDFN8 MT SUFFIX CASE 511CF







(Top View)

### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information in the package dimensions section on page 7 of this data sheet.

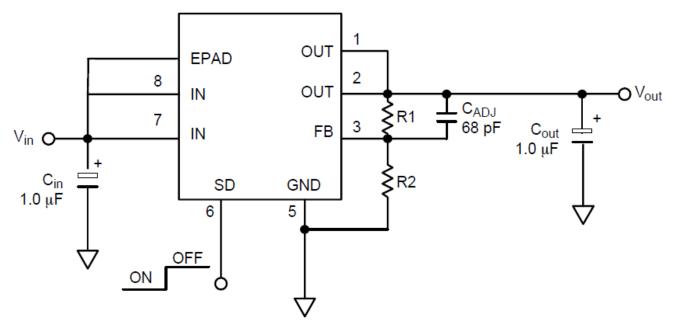


Figure 1. Typical Adjustable Version Application Schematic

### **PIN FUNCTION DESCRIPTION**

Pin No.	Pin Name	Description		
1, 2	V <sub>out</sub>	Regulated output voltage. Bypass to ground with $C_{out} \ge 1.0 \mu\text{F}.$		
3	FB	Adjustable pin; reference voltage = 1.178 V.		
4	NC	Not Connected		
5	GND	Power Supply Ground		
6	SD	Shutdown pin. Pulling this pin Low turns on the regulator		
7, 8	V <sub>in</sub>	Power Supply Input Voltage		
-	EPAD	Exposed thermal pad should be connected to ground or Vin. The EPAD is electrically isolated from the die.		

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage	V <sub>in</sub>	–0.3 to +16	V
Output Voltage	V <sub>out</sub>	–0.3 to V <sub>in</sub> +0.3 or 10 V*	V
Shutdown Pin Voltage	V <sub>sh</sub>	–0.3 to +16	V
Junction Temperature Range	TJ	-40 to +150	°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. NOTE: This device series contains ESD protection and exceeds the following tests:

Human Body Model (HBM) JESD 22-A114-B

\*Which ever is less. Reverse bias protection feature valid only if V<sub>out</sub> – V<sub>in</sub>  $\leq$  7 V.

#### THERMAL CHARACTERISTICS

	Test Conditions (Typical Value)		
Characteristic	Min Pad Board	1" Pad Board (Note 1)	Unit
WDFN 8			
Junction-to-Air. 0JA	220	48	°C/W

1. As mounted on 4-Layer FR4 Substrate of a specified copper area of 2 oz copper traces in accordance with JEDEC 51.7.

### ELECTRICAL CHARACTERISTICS – Adjustable

 $(V_{out} = 1.178 \text{ V typical}, V_{in} = 6.0 \text{ V}, T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, C_{in} = C_{out} = 1 \mu\text{F}$ , unless otherwise noted, Note 2, 3, 4)

Symbol	Min	Тур	Max	Unit
V <sub>ref</sub>	–0.9% 1.167	1.178	+0.9% 1.189	V
V <sub>ref</sub>	–1.4% 1.162	1.178	+1.4% 1.194	V
V <sub>ref</sub>	–1.5% 1.160	1.178	+1.5% 1.196	V
Line <sub>Reg</sub>		0.04		mV/V
Load <sub>Reg</sub>		0.04		mV/mA
V <sub>DO</sub>		- - - 10	340 230 140 -	mV
lpk	500	700	860	mA
TJ		160		°C
I <sub>GND</sub>		6.0 3.5 0.7 130	10 6 1.5 180	mA μA
		-	450	μΑ
I <sub>GNDsh</sub>		8	20	μΑ
V <sub>noise</sub>		26 38		μVrms
V <sub>THSD</sub>	2.0		0.4	V V
I <sub>SD</sub>		1.2	3.0	μΑ
I <sub>OSD</sub>		0.07	1.0	μΑ
I <sub>OUTR</sub>		1.0		μΑ
	Vref Vref Vref Line <sub>Reg</sub> Load <sub>Reg</sub> VDO Ipk TJ IGND IgNDsh Vnoise Vroise Vroise VTHSD ISD	Vref       -0.9%         Vref       -1.4%         Vref       -1.5%         LineReg       -1.5%         LoadReg       -0.9%         Vref       -1.4%         LineReg       -0.9%         LoadReg       -0.9%         VDO       -0.9%         Ipk       500         TJ       -0.9%         IgND       -1.5%         IgND       -0.9%         VDO       -0.9%         VDO       -0.9%         VDO       -0.9%         VDO       -0.9%         IgND       -0.9%         Vnoise       -0.9%         VTHSD       2.0         ISD       -0.9%	Vref       -0.9%       1.178 $V_{ref}$ -1.4%       1.178 $V_{ref}$ -1.5%       1.178 $V_{ref}$ -1.5%       1.178         Line <sub>Reg</sub> 0.04         Load <sub>Reg</sub> 0.04 $V_{DO}$ - $V_{DO}$ -         Ipk       500 $I_{GND}$ 6.0 $I_{GND}$ 6.0 $I_{GND}$ - $I_{GNDsh}$ 8 $V_{noise}$ 26 $V_{THSD}$ 2.0 $I_{SD}$ 1.2 $I_{OSD}$ 0.07	$V_{ref}$ $-0.9\%$ $1.178$ $+0.9\%$ $V_{ref}$ $-1.4\%$ $1.178$ $+1.4\%$ $V_{ref}$ $-1.5\%$ $1.178$ $+1.5\%$ $V_{ref}$ $-1.5\%$ $1.178$ $+1.5\%$ $Line_{Reg}$ $0.04$ $1.194$ $V_{ref}$ $-1.5\%$ $1.178$ $+1.5\%$ $Line_{Reg}$ $0.04$ $1.196$ $1.196$ $V_{DO}$ $ 340$ $230$ $V_{DO}$ $ 340$ $230$ $V_{DO}$ $ 340$ $230$ $Igk$ $500$ $700$ $860$ $T_J$ $160$ $ 230$ $IgND$ $6.0$ $10$ $ IGND$ $ 450$ $1.2$ $I_{GNDsh}$ $ 450$ $ I_{GNDsh}$ $8$ $20$ $ V_{noise}$ $2.0$ $0.4$ $ V_{THSD}$ $2.0$ $0.4$ $0.4$ $I_{SD}$ $1.2$ $3.0$ $0.07$

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

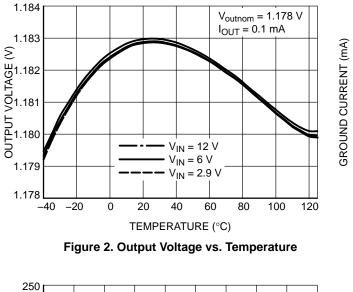
2. All limits at temperature extremes are guaranteed via correlation using standard statistical quality control (SQC) methods.

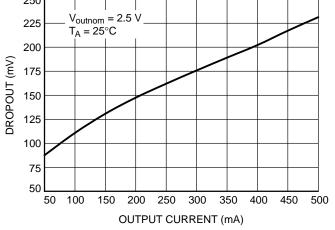
3. Ambient temperature of 85°C corresponds to a junction temperature of 125°C under pulsed full load test conditions.

4. Application stable with no load.

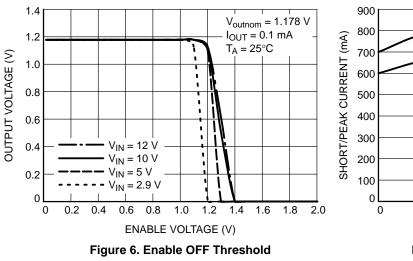
5.  $V_{IN} = 2.6 \text{ V}$  to 11 V for  $V_{OUT(NOM)} \le 2.2 \text{ V}$  and  $T_J > 0^{\circ}C$ , otherwise  $V_{IN} = 2.9 \text{ V}$  to 11 V. 6. Reverse bias protection feature valid only if  $V_{out} - V_{in} \le 7 \text{ V}$ .

### **TYPICAL CHARACTERISTICS**









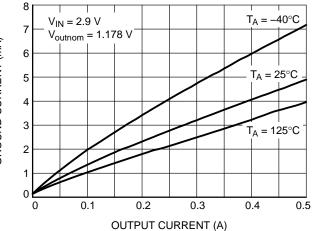


Figure 3. Ground Current vs. Output Current

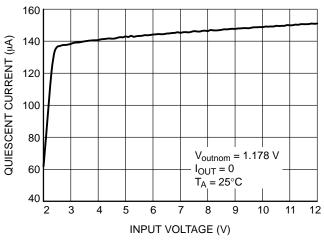
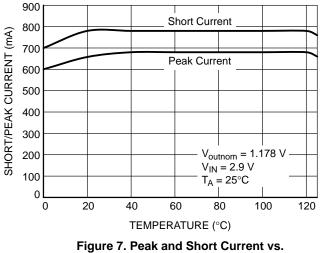
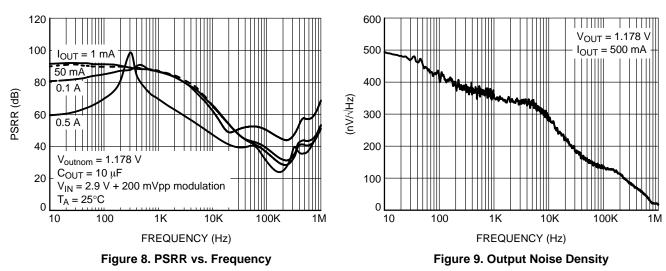


Figure 5. Quiescent Current vs. Input Voltage



Temperature



### **TYPICAL CHARACTERISTICS**

### **APPLICATIONS INFORMATION**

### **Reverse Bias Protection**

Reverse bias is a condition caused when the input voltage goes to zero, but the output voltage is kept high either by a large output capacitor or another source in the application which feeds the output pin.

Normally in a bipolar LDO all the current will flow from the output pin to input pin through the PN junction with limited current capability and with the potential to destroy the IC.

Due to an improved architecture, the NCP3334A can withstand up to 7.0 V on the output pin with virtually no current flowing from output pin to input pin, and only negligible amount of current (tens of  $\mu$ A) flowing from the output pin to ground for infinite duration.

### **Input Capacitor**

An input capacitor of at least  $1.0 \ \mu\text{F}$ , any type, is recommended to improve the transient response of the regulator and/or if the regulator is located more than a few inches from the power source. It will also reduce the circuit's sensitivity to the input line impedance at high frequencies. The capacitor should be mounted with the shortest possible track length directly across the regular's input terminals.

### **Output Capacitor**

The NCP3334A remains stable with any type of capacitor as long as it fulfills its 1.0  $\mu$ F requirement. There are no constraints on the minimum ESR and it will remain stable up to an ESR of 5.0  $\Omega$ . Larger capacitor values will improve the noise rejection and load transient response.

### **Adjustable Operation**

The output voltage can be set by using a resistor divider with a range of 1.178 to 10 V. The appropriate resistor divider can be found by solving the equation below. The recommended current through the resistor divider is from 10  $\mu$ A to 100  $\mu$ A. This can be accomplished by selecting resistors in the k $\Omega$  range. As result, the I<sub>adj</sub>\*R2 becomes negligible in the equation and can be ignored.

$$V_{out} = 1.178 * \left(1 + \frac{R1}{R2}\right) + I_{adj} * R2$$
 (eq. 1)

### **Dropout Voltage**

The voltage dropout is measured at 97% of the nominal output voltage.

### **Thermal Considerations**

Internal thermal limiting circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. This feature provides protection from a catastrophic device failure due to accidental overheating. This protection feature is not intended to be used as a substitute to heat sinking. The maximum power that can be dissipated, can be calculated with the equation below:

$$\mathsf{P}_\mathsf{D} = \frac{\mathsf{T}_\mathsf{J}(\mathsf{max}) - \mathsf{T}_\mathsf{A}}{\mathsf{R}_\theta \mathsf{J}_\mathsf{A}} \tag{eq. 2}$$

For improved thermal performance, contact the factory for the WDFN package option. The WDFN package includes an exposed metal pad that is specifically designed to reduce the junction to air thermal resistance,  $R_{\theta JA}$ .

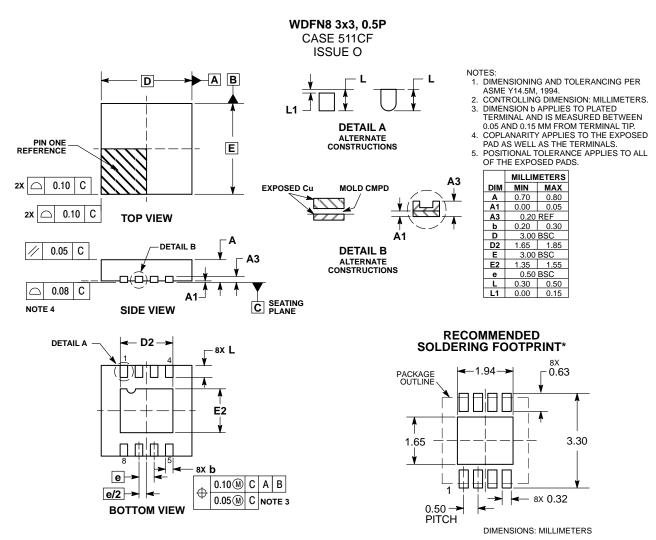
### **ORDERING INFORMATION**

Device	Nominal Output Voltage	Marking	Package	Shipping <sup>†</sup>
NCP3334AMTADJTBG	Adj.	3334A ADJ	WDFN8 (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*Please contact factory for other voltage options.

#### PACKAGE DIMENSIONS



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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